

Abstract Submitted
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Physical adsorption induced band gap opening in graphene YOU-
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— Gapping graphene is crucial for enabling its use in next-generation electronic de-
vices. Here we show that physical adsorption of suitable aromatic molecules onto
graphene can generate a moderate band gap of approximately 0.125 eV, with an
adsorption energy 0.67 eV. The reason for such a band gap is that the Lowest un-
occupied molecule orbit of adsorbate is right across the Fermi level of graphene and
thus generate a big perturbation on graphene Dirac point energy level.

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